## VS-10MQ060-M3

SHAY, www.vishay.com

**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 1 A



SMA (DO-214AC)

### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>R</sub>	60 V			
V <sub>F</sub> at I <sub>F</sub>	0.57 V			
I <sub>RM</sub>	7.5 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	2.0 mJ			
Package	SMA (DO-214AC)			
Circuit configuration	Single			

### FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

The VS-10MQ060-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	1	A		
V <sub>RRM</sub>		60	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	40	A		
V <sub>F</sub>	1.5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.63	V		
TJ	Range	-55 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10MQ060-M3	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	60	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I <sub>F(AV)</sub>	50 % duty cycle at $T_L$ = 120 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		1.5	A
		50 % duty cycle at $T_L$ = 129 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		1	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	40	
non-repetitive surge current I <sub>FS</sub> See fig. 6	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	10	A
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 4 mH		2.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.0	А

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RoHS COMPLIANT HALOGEN

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1		1 A	T <sub>J</sub> = 25 °C	0.63	V
	V <sub>FM</sub> <sup>(1)</sup>	1.5 A		0.71	
	VFM ("	1 A	- T <sub>J</sub> = 125 °C	0.57	
		1.5 A		0.63	
Maximum reverse leakage current See fig. 2	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.5	mA
		T <sub>J</sub> = 125 °C		7.5	
Threshold voltage	V <sub>F(TO)</sub>	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.45	V
Forward slope resistance	r <sub>t</sub>			mΩ	
Typical junction capacitance	CT	$V_{R} = 10 V_{DC}, T_{J} = 25 \text{ °C}, \text{ test signal} = 1 \text{ MHz}$ 31		31	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 2.0		nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µs		V/µs	

#### Note

 $^{(1)}\,$  Pulse width = 300  $\mu s,$  duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_{J}$ <sup>(1)</sup> , $T_{Stg}$		-55 to +150	°C
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	°C/W
Approximate weight			0.07	g
			0.002	oz.
Marking device		Case style SMA (DO-214AC)	1	Н

### Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ 

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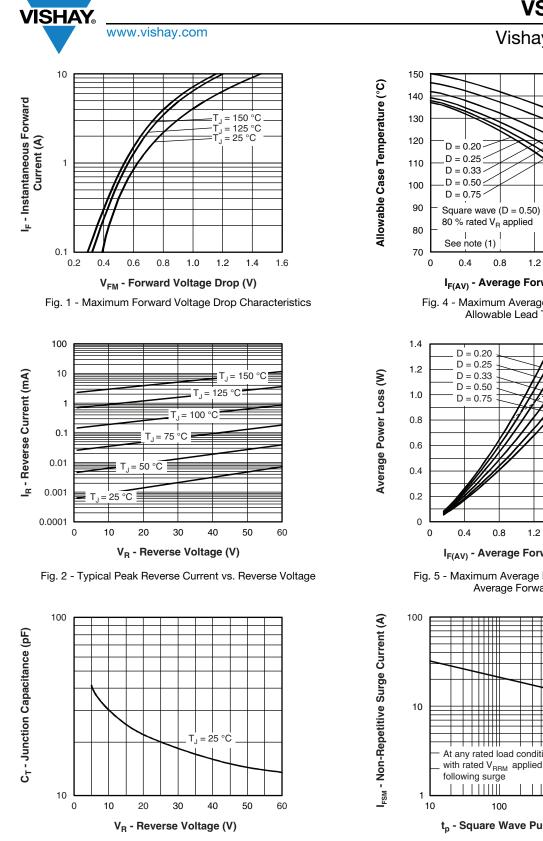


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd<sub>REV</sub> = inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

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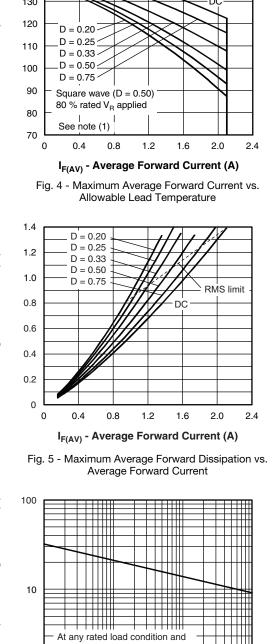
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10 000 1000 100 t<sub>p</sub> - Square Wave Pulse Duration (μs)

Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

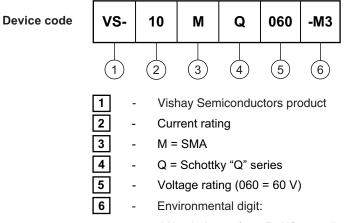
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### **ORDERING INFORMATION TABLE**

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-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCR				
VS-10MQ060-M3/5AT	5AT	7500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95400		
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		

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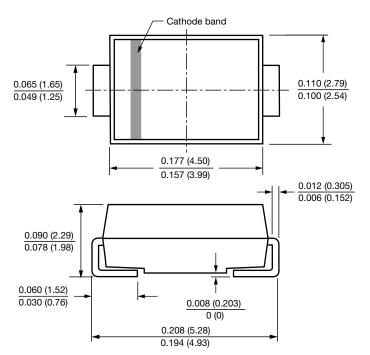


## **Outline Dimensions**

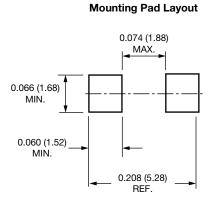
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**SMA** 

### **DIMENSIONS** in inches (millimeters)



### DO-214AC (SMA)







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